PS9531, PS9531L1,

RENESAS

## DESCRIPTION

The PS9531, PS9531L1, PS9531L2 and PS9531L3 are optically coupled isolators containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

The PS9531 Series is designed specifically for high common mode transient immunity (CMR), high output current and high switching speed.

The PS9531 Series is suitable for driving IGBTs and MOS FETs.

The PS9531 Series is in a plastic DIP (Dual In-line Package).

The PS9531L1 is lead bending type for long creepage distance.

The PS9531L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

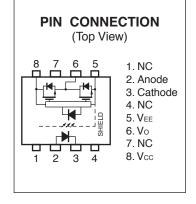
The PS9531L3 is lead bending type (Gull-wing) for surface mounting.

## FEATURES

- Long creepage distance (8 mm MIN.: PS9531L1, PS9531L2)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching ( $t_{PLH}$ ,  $t_{PHL} = 175$  ns MAX.)
- UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CM<sub>H</sub>, CM<sub>L</sub> =  $\pm 50 \text{ kV}/\mu \text{s MIN.}$ )
- Embossed tape product : PS9531L2-E3: 1 000 pcs/reel
  - : PS9531L3-E3: 1 000 pcs/reel
- <R> Pb-Free product
  - Safety standards
    - UL approved: No. E72422
    - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
    - SEMKO approved (EN 60065, EN 60950)
    - DIN EN 60747-5-5 (VDE 0884-5) approved (Option)

## APPLICATIONS

- IGBT, Power MOS FET Gate Driver
- Industrial inverter
- IH (Induction Heating)



The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.

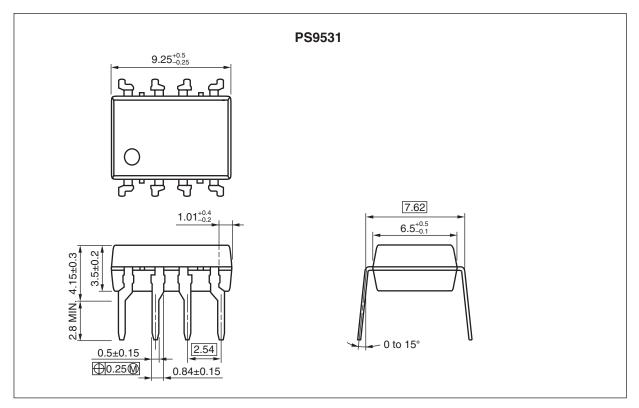


# Data Sheet

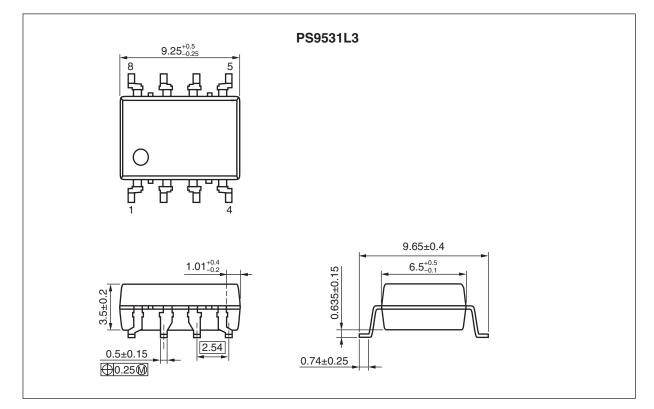
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## PACKAGE DIMENSIONS (UNIT: mm)

## **DIP** Type



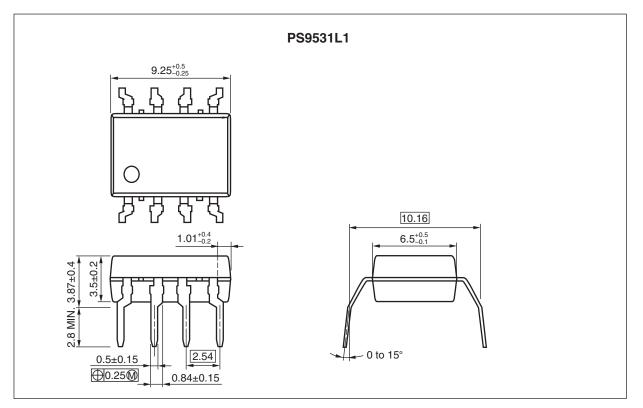
## Lead Bending Type (Gull-wing) For Surface Mount



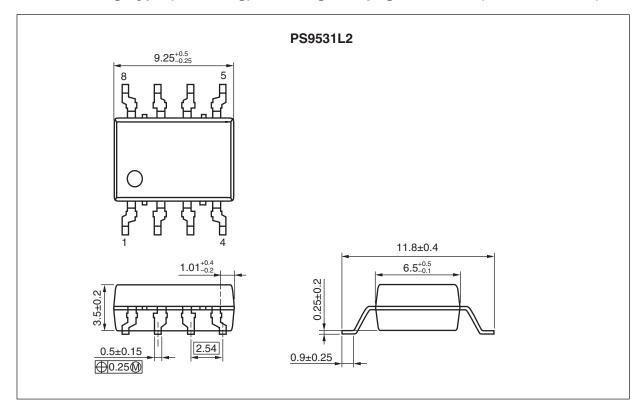




## Lead Bending Type For Long Creepage Distance



## Lead Bending Type (Gull-wing) For Long Creepage Distance (Surface Mount)

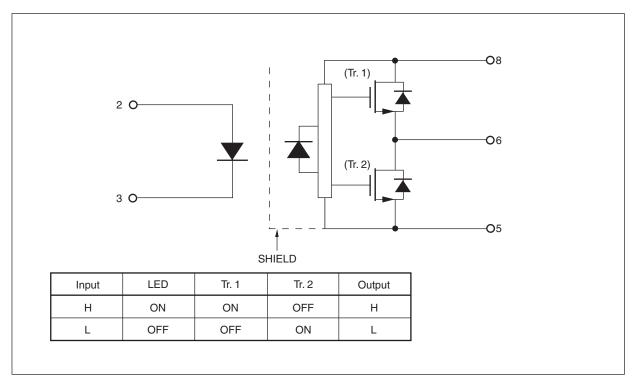




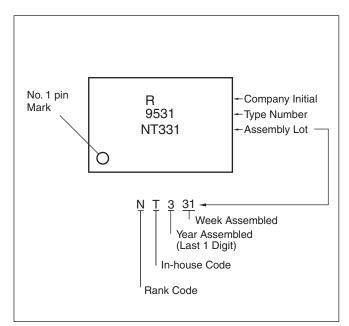
## PHOTOCOUPLER CONSTRUCTION

Parameter	PS9531, PS9531L3	PS9531L1, PS9531L2
Air Distance (MIN.)	7 mm	8 mm
Outer Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

## FUNCTIONAL DIAGRAM



### MARKING EXAMPLE







### **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number <sup>*1</sup>
PS9531	PS9531-AX	Pb-Free	50 Magazine Cases	Standard	PS9531
PS9531L1	PS9531L1-AX	(Ni/Pd/Au)		products	PS9531L1
PS9531L2	PS9531L2-AX			(UL, CSA, SEMKO	PS9531L2
PS9531L3	PS9531L3-AX			approved)	PS9531L3
PS9531L2-E3	PS9531L2-E3-AX		Embossed Tape		PS9531L2
PS9531L3-E3	PS9531L3-E3-AX		1 000 pcs/reel		PS9531L3
PS9531-V	PS9531-V-AX		50 Magazine Cases	UL, CSA, SEMKO,	PS9531
PS9531L1-V	PS9531L1-V-AX			DIN EN 60747-5-5	PS9531L1
PS9531L2-V	PS9531L2-V-AX			(VDE 0884-5)	PS9531L2
PS9531L3-V	PS9531L3-V-AX			approved	PS9531L3
PS9531L2-V-E3	PS9531L2-V-E3-AX	1	Embossed Tape	]	PS9531L2
PS9531L3-V-E3	PS9531L3-V-E3-AX	]	1 000 pcs/reel		PS9531L3

Note: \*1. For the application of the Safety Standard, following part number should be used.



## ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ , unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current	I <sub>F</sub>	25	mA
	Peak Transient Forward Current (Pulse Width < 1 μs)	I <sub>F (TRAN)</sub>	1.0	A
	Reverse Voltage	V <sub>R</sub>	5	V
	Power Dissipation *1	PD	45	mW
Detector	High Level Peak Output Current *2	I <sub>OH (PEAK)</sub>	2.5	A
	Low Level Peak Output Current *2	I <sub>OL (PEAK)</sub>	2.5	A
	Supply Voltage		0 to 35	V
	Output Voltage	Vo	0 to V <sub>CC</sub>	V
	Power Dissipation *3	Pc	250	mW
Isolation \	Isolation Voltage *4		5 000	Vr.m.s.
Operating Frequency		f	50	kHz
Operating	Operating Ambient Temperature		-40 to +125	°C
Storage T	emperature	T <sub>stg</sub>	–55 to +150	°C

Notes: \*1. Reduced to 1.5 mW/°C at  $T_A = 110^{\circ}C$  or more.

\*2. Maximum pulse width = 10  $\mu$ s, Maximum duty cycle = 0.2%

\*3. Reduced to 3.9 mW/°C at  $T_A$  = 90°C or more.

\*4. AC voltage for 1 minute at  $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.

## **RECOMMENDED OPERATING CONDITIONS**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	$(V_{CC} - V_{EE})$	15		30	V
Forward Current (ON)	I <sub>F (ON)</sub>	8	10	12	mA
Forward Voltage (OFF)	V <sub>F (OFF)</sub>	-2		0.8	V
Operating Ambient Temperature	T <sub>A</sub>	-40		125	°C



## ELECTRICAL CHARACTERISTICS (at RECOMMENDED OPERATING CONDITIONS, $V_{EE}$ = GND, unless otherwise specified)

	Parameter		Conditions	MIN.	TYP. <sup>*1</sup>	MAX.	Unit
Diode	Forward Voltage	VF	I <sub>F</sub> = 10 mA, T <sub>A</sub> = 25°C	1.35	1.56	1.75	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> = 3 V, T <sub>A</sub> = 25°C			10	μA
	Input Capacitance	CIN	f = 1 MHz, V <sub>F</sub> = 0 V		30		pF
Detector	High Level Output Current	I <sub>ОН</sub>	$V_0 = (V_{CC} - 4 V)^{*2}$	0.5	2.2		А
			$V_{\rm O}$ = $(V_{\rm CC} - 15 \text{ V})^{*3}$	2.0			
	Low Level Output Current	I <sub>OL</sub>	$V_{\rm O} = (V_{\rm EE} + 2.5 \text{ V})^{*2}$	0.5	2.4		А
			$V_{\rm O} = (V_{\rm EE} + 15 \text{ V})^{*3}$	2.0			
	High Level Output Voltage	V <sub>OH</sub>	I <sub>O</sub> = -100 mA <sup>*4</sup>	$V_{CC}-3.0$	$V_{CC}-1.3$		V
	Low Level Output Voltage	V <sub>OL</sub>	I <sub>0</sub> = 100 mA		0.2	0.5	V
	High Level Supply Current	I <sub>CCH</sub>	V <sub>o</sub> = Open		1.7	2.2	mA
	Low Level Supply Current	I <sub>CCL</sub>	V <sub>o</sub> = Open		1.7	2.2	mA
	UVLO Threshold	V <sub>UVLO+</sub>	V <sub>O</sub> > 5 V, I <sub>F</sub> = 10 mA	10.8	12.3	13.4	V
		V <sub>UVLO</sub> -		9.5	11.0	12.5	
	UVLO Hysteresis	UVLO <sub>HYS</sub>	$V_{\rm O}$ > 5 V, I <sub>F</sub> = 10 mA	0.4	1.3		V
Coupled	Threshold Input Current $(L \rightarrow H)$	I <sub>FLH</sub>	I <sub>O</sub> = 0 mA, V <sub>O</sub> > 5 V		2.0	4.0	mA
	Threshold Input Voltage $(H \rightarrow L)$	$V_{FHL}$	I <sub>O</sub> = 0 mA, V <sub>O</sub> < 5 V	0.8			V

Notes: \*1. Typical values at  $T_A$  = 25°C,  $V_{CC}-V_{EE}$  = 30 V.

\*2. Maximum pulse width = 50  $\mu$ s, Maximum duty cycle = 0.5%.

\*3. Maximum pulse width = 10  $\mu$ s, Maximum duty cycle = 0.2%.

\*4. V<sub>OH</sub> is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).

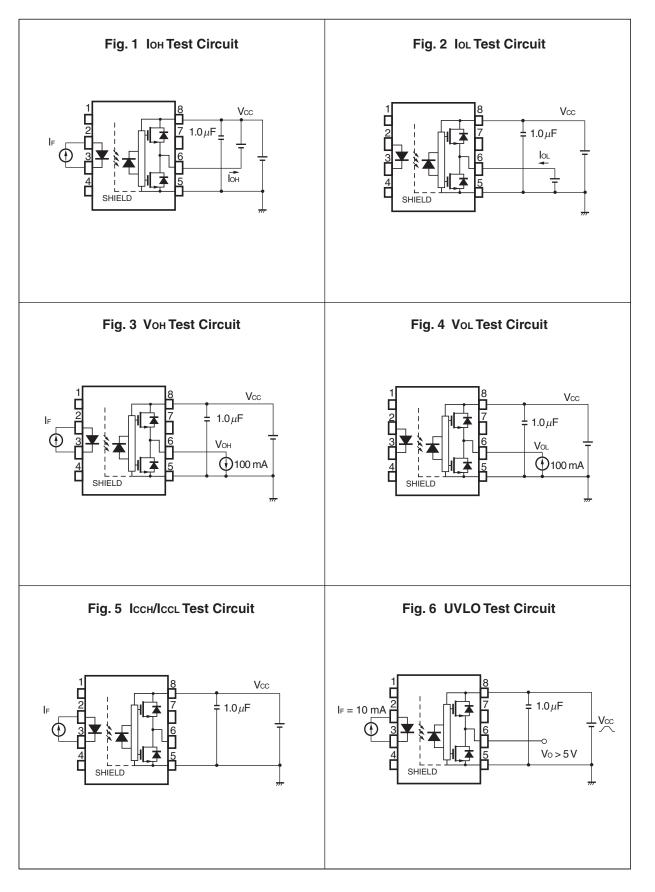
## SWITCHING CHARACTERISTICS (at RECOMMENDED OPERATING CONDITIONS, $V_{EE}$ = GND, unless otherwise specified)

Parameter	Symbol	Conditions	MIN.	TYP. <sup>*1</sup>	MAX.	Unit
Propagation Delay Time (L $\rightarrow$ H)	t <sub>PLH</sub>	$R_g$ = 10 $\Omega$ , $C_g$ = 10 nF,		80	175	ns
Propagation Delay Time (H $\rightarrow$ L)	t <sub>PHL</sub>	f = 10 kHz,		100	175	ns
Pulse Width Distortion (PWD)	t <sub>PHL</sub> -t <sub>PLH</sub>	Duty Cycle = 50%,		20	75	ns
Propagation Delay Time (Difference Between Any Two Products)	t <sub>PHL</sub> —t <sub>PLH</sub>	I <sub>F</sub> = 10 mA	-90		90	ns
Rise Time	tr			40		ns
Fall Time	t <sub>f</sub>			40		ns
Common Mode Transient Immunity at High Level Output	CM <sub>H</sub>	$T_A = 25^{\circ}C$ , $I_F = 10 \text{ mA}$ , $V_{CC} = 30 \text{ V}$ , $V_{CM} = 1.5 \text{ kV}$	50			kV/ <i>µ</i> s
Common Mode Transient Immunity at Low Level Output	CM∟	$T_A = 25^{\circ}C, I_F = 0 \text{ mA},$ $V_{CC} = 30 \text{ V}, V_{CM} = 1.5 \text{ kV}$	50			kV/ <i>µ</i> s

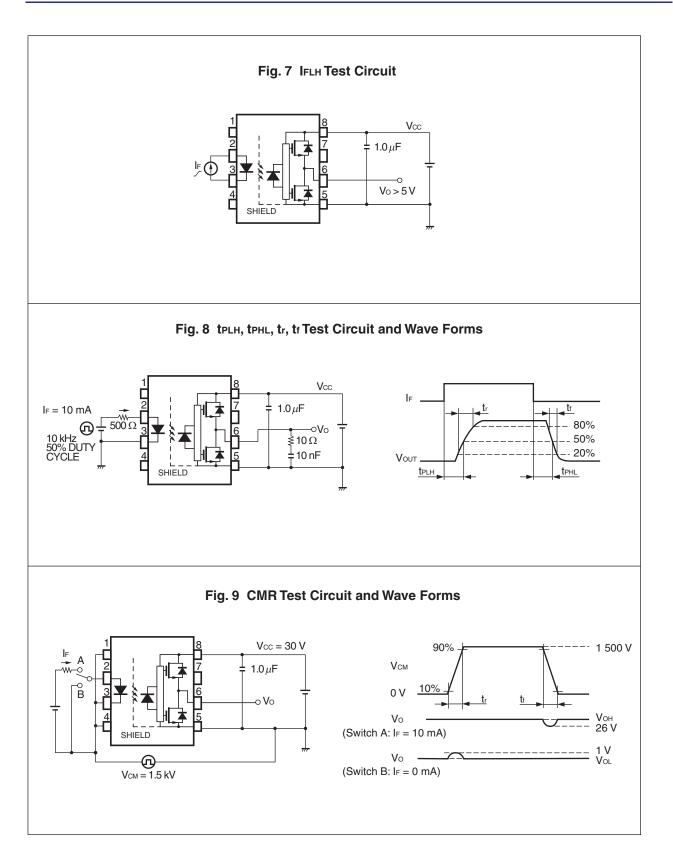
Note: \*1. Typical values at  $T_A = 25^{\circ}C$ ,  $V_{CC}-V_{EE} = 30 V$ .



## **TEST CIRCUIT**



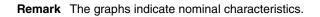






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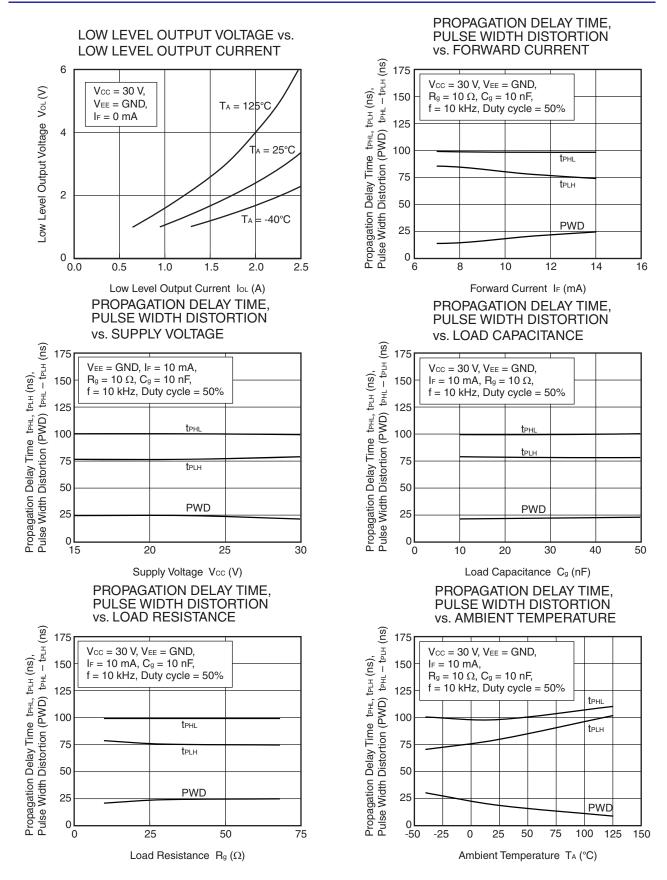
#### TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ , unless otherwise specified) DETECTOR POWER DISSIPATION **DIODE POWER DISSIPATION** vs. AMBIENT TEMPERATURE vs. AMBIENT TEMPERATURE 50 300 Detector Power Dissipation Pc (mW) Diode Power Dissipation PD (mW) 250 40 200 30 150 20 100 10 50 0 25 50 75 100 125 150 0 25 50 75 100 125 150 Ambient Temperature T<sub>A</sub> (°C) Ambient Temperature T<sub>A</sub> (°C) FORWARD CURRENT vs. THRESHOLD INPUT CURRENT vs. FORWARD VOLTAGE AMBIENT TEMPERATURE 100 3 Vcc = 30 V, Threshold Input Current IFLH/ IFHL (mA) VEE = GND. FLH $V_{\text{th}} = 5 \text{ V}$ 10 Forward Current IF (mA) 2 T<sub>A</sub> = 125°C 1 -100°C -85°C 1 50°C FHL 0.1 25°C -20°C -40°C 0.01 0 -25 1.6 1.8 2.0 2.2 2.4 -50 25 50 75 100 125 150 1.0 1.2 1.4 0 Forward Voltage VF (V) Ambient Temperature TA (°C) HIGH LEVEL OUTPUT VOLTAGE - SUPPLY OUTPUT VOLTAGE vs. FORWARD CURRENT VOLTAGE vs. HIGH LEVEL OUTPUT CURRENT 35 0 Vcc = 30 V,High Level Output Voltage – Supply Vcc = 30 V, 30 VEE = GND, $V_{\text{EE}} = GND$ -1 I⊧ = 10 mA Output Voltage Vo (V) 25 -2 -40°C TA 20 Voltage VoH – Vcc (V) -3 15 -4 A = 25 10 $T_A = 125^{\circ}C$ -5 5 -6 **L** 0.0 0 0.5 1.0 2.0 2.5 0 2 3 1.5 1 Forward Current IF (mA) High Level Output Current IOH (A)

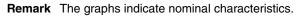


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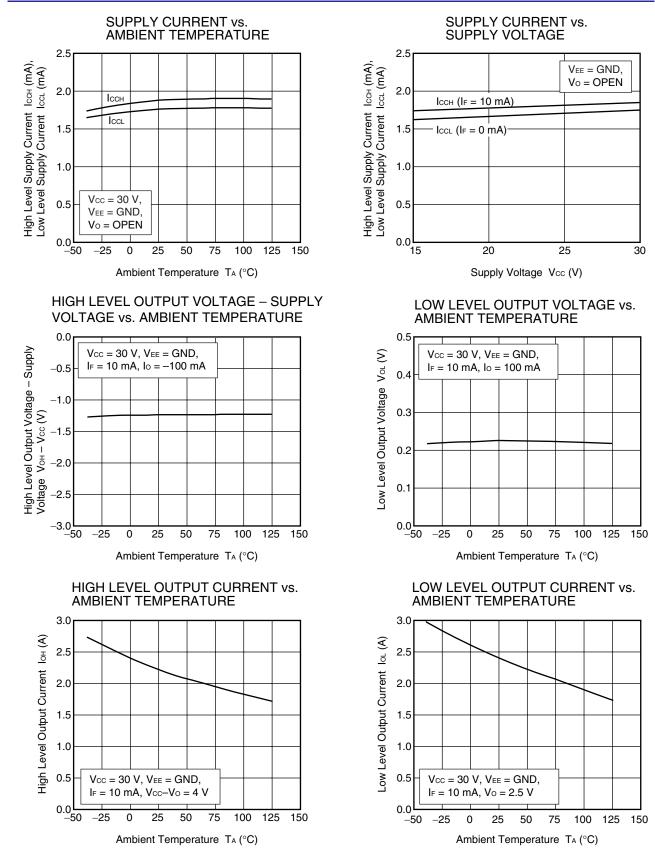




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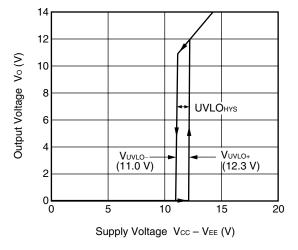




Remark The graphs indicate nominal characteristics.



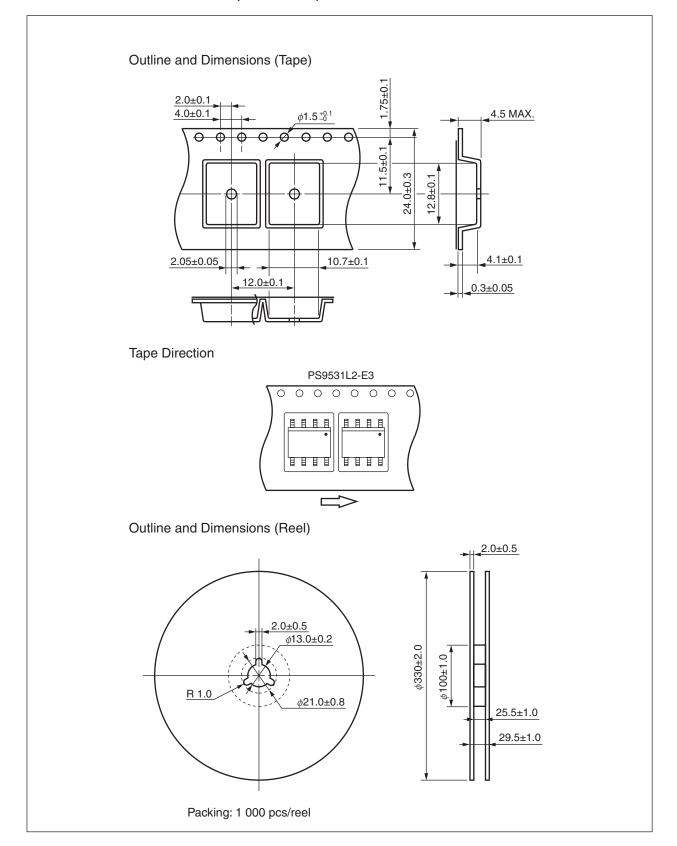
#### OUTPUT VOLTAGE vs. SUPPLY VOLTAGE



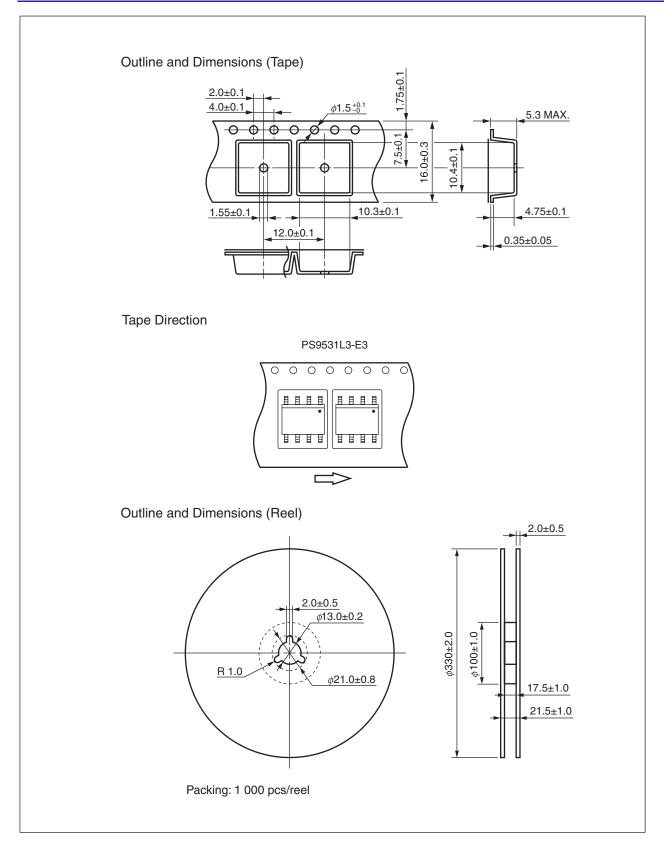
**Remark** The graphs indicate nominal characteristics.



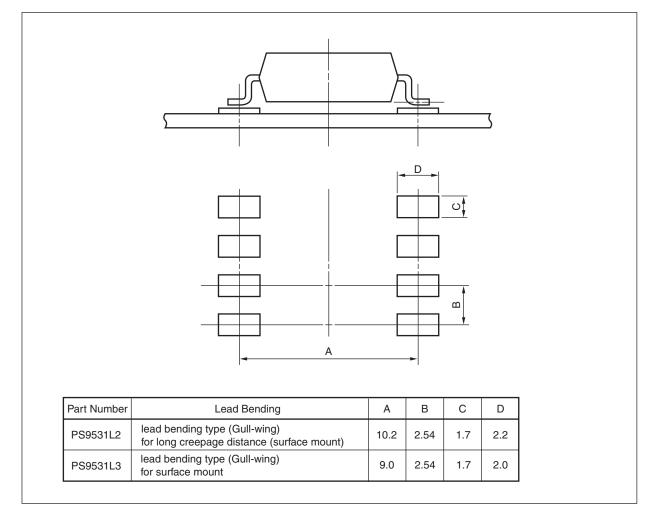
## TAPING SPECIFICATIONS (UNIT: mm)







## **RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)**







## NOTES ON HANDLING

- 1. Recommended soldering conditions
- (1) Infrared reflow soldering
  - · Peak reflow temperature
  - Time of peak reflow temperature
  - Time of temperature higher than 220°C
  - Time to preheat temperature from 120 to 180°C
  - Number of reflows

10 seconds or less

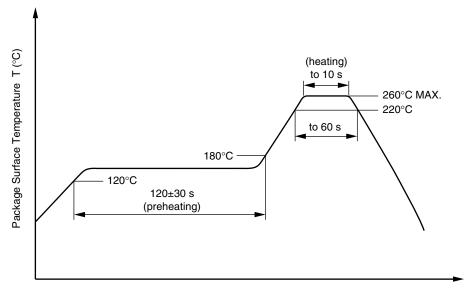
260°C or below (package surface temperature)

- 60 seconds or less
- 120±30 s Three

• Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

### Recommended Temperature Profile of Infrared Reflow





#### (2) Wave soldering

#### • Temperature

- Time 10 seconds or less
- · Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)

260°C or below (molten solder temperature)

• Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

#### (3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a
	maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead



#### (4) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

## **USAGE CAUTIONS**

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. Board designing
  - (1) By-pass capacitor of more than 1.0  $\mu$ F is used between VCC and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
  - (2) When designing the printed wiring board, ensure that the pattern of the IGBT collectors/emitters is not too close to the input block pattern of the photocoupler.

If the pattern is too close to the input block and coupling occurs, a sudden fluctuation in the voltage on the IGBT output side might affect the photocoupler's LED input, leading to malfunction or degradation of characteristics.

(If the pattern needs to be close to the input block, to prevent the LED from lighting during the off state due to the abovementioned coupling, design the input-side circuit so that the bias of the LED is reversed, within the range of the recommended operating conditions, and be sure to thoroughly evaluate operation.)

(3) Pins 1, 4 (which is an NC<sup>\*1</sup> pin) can either be connected directly to the GND pin on the LED side or left open. Pin 7, which is an NC<sup>\*1</sup> pin, can either be connected directly to Pin 6 or the GND pin on the output side (photo diode side), or left open.

Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.

\*1 NC: Non-Connection (No Connection)

- 3. Make sure the rise/fall time of the forward current is 0.5  $\mu$ s or less.
- 4. In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is  $3 V/\mu s$  or less.
- 5. Avoid storage at a high temperature and high humidity.



## SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 130	$V_{peak}$
Test voltage (partial discharge test, procedure a for type test and random test)	U <sub>pr</sub>	1 808	$V_{peak}$
$U_{pr}$ = 1.6 × $U_{IORM}$ , $P_d$ < 5 pC			
Test voltage (partial discharge test, procedure b for all devices)	U <sub>pr</sub>	2 119	$V_{peak}$
$U_{pr}$ = 1.875 $\times$ $U_{IORM}$ , $P_d$ < 5 pC			
Highest permissible overvoltage	U <sub>TR</sub>	8 000	$V_{\text{peak}}$
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	T <sub>stg</sub>	-55 to +150	°C
Operating temperature range	T <sub>A</sub>	-40 to +125	°C
Isolation resistance, minimum value			
$V_{IO}$ = 500 V dc at $T_A$ = 25°C	Ris MIN.	10 <sup>12</sup>	Ω
$V_{IO}$ = 500 V dc at T <sub>A</sub> MAX. at least 100°C	Ris MIN.	10 <sup>11</sup>	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I <sub>F</sub> , Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
$V_{IO}$ = 500 V dc at $T_A$ = Tsi	Ris MIN.	10 <sup>9</sup>	Ω





Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	<ul> <li>Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.</li> </ul>
	<ol> <li>Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.</li> </ol>
	<ol><li>Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.</li></ol>
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	Do not lick the product or in any way allow it to enter the mouth.



**Revision History** 

PS9531, PS9531L1, PS9531L2, PS9531L3 Data Sheet

			Description		
Rev.	Date	Page	Summary		
0.01	Jul 08, 2013	-	First Edition issued		
1.00	Nov 29, 2013	Throughout	Preliminary Data Sheet -> Data Sheet		
		Throughout	Safety standards approved		

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